

COST

European Network on New Sensing Technologies for Air Pollution Control and Environmental Sustainability - *EuNetAir*

COST Action TD1105

2nd International Workshop *EuNetAir* on

New Sensing Technologies for Indoor and Outdoor Air Quality Control

ENEA - Brindisi Research Center, Brindisi, Italy, 25 - 26 March 2014

**Low Power and Portable AlGaIn/GaN based Sensor Systems
for Air Monitoring**



Rob van Schaijk

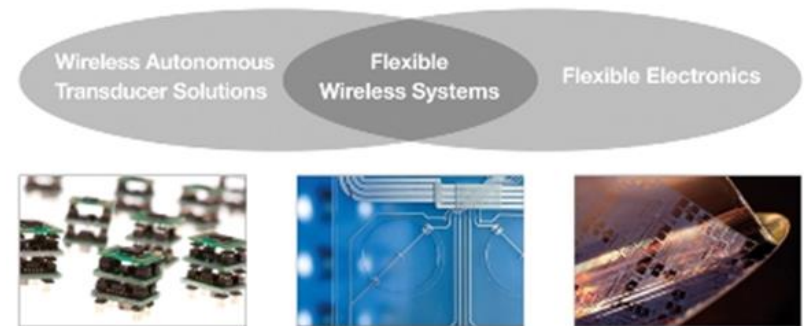
Function in the Action: Expert

Imec / Holst Centre, The Netherlands

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Holst Centre Fundamentals

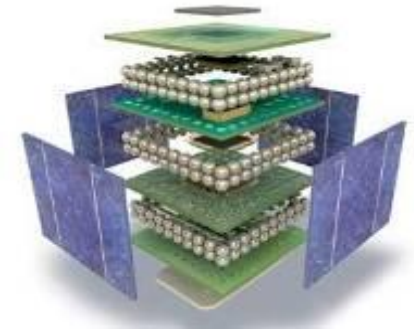
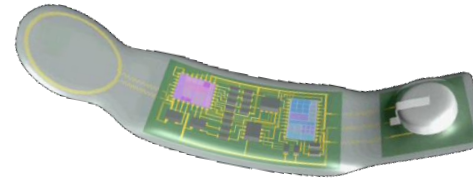
- **Independent, with reputed parents**
 - Founded by imec (1300 fte, Belgium) and TNO (4500 fte, The Netherlands)
 - Operational since 2006
- **Critical mass to create impact**
 - Staff of 180 researchers; >28 nationalities
 - Involving groups of mother organisations
 - 70 industrial and academic residents
- **Focus on relevant topics**
 - Ultra-low-power and flexible electronics
 - Lighting, Solar, Displays, Healthcare
- **Supported by strong eco-system**
 - Global industrial and academic partners
 - Embedded in high-tech region
- **Co-funded by local and Dutch government**
 - Fastest growing R&D consortium in the Netherlands



Wireless Autonomous Transducer Solutions

Cover all basic building blocks of a wireless sensor node

- Digital signal processing
- Wireless communication
- Micro-power generation and storage
- Sensor and actuator technology
- Analog IC design

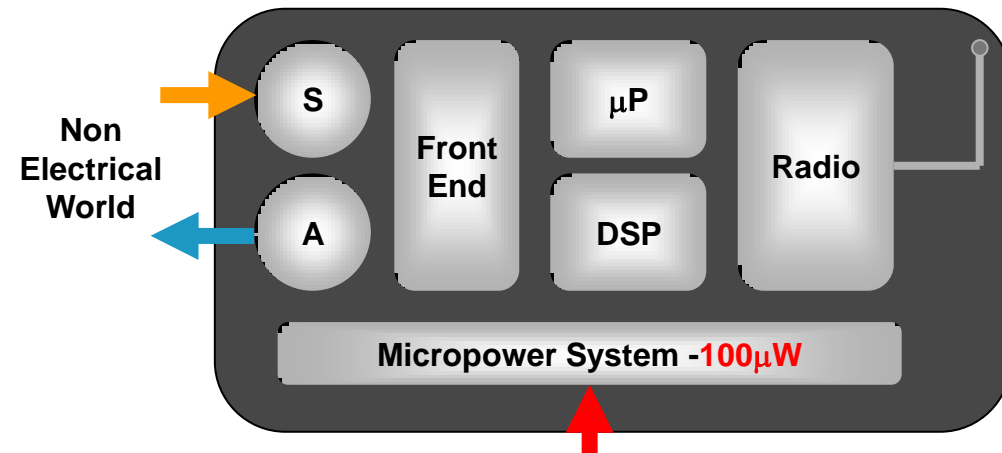


Integration in various form factors

- 3D stack
- Flexible / stretchable

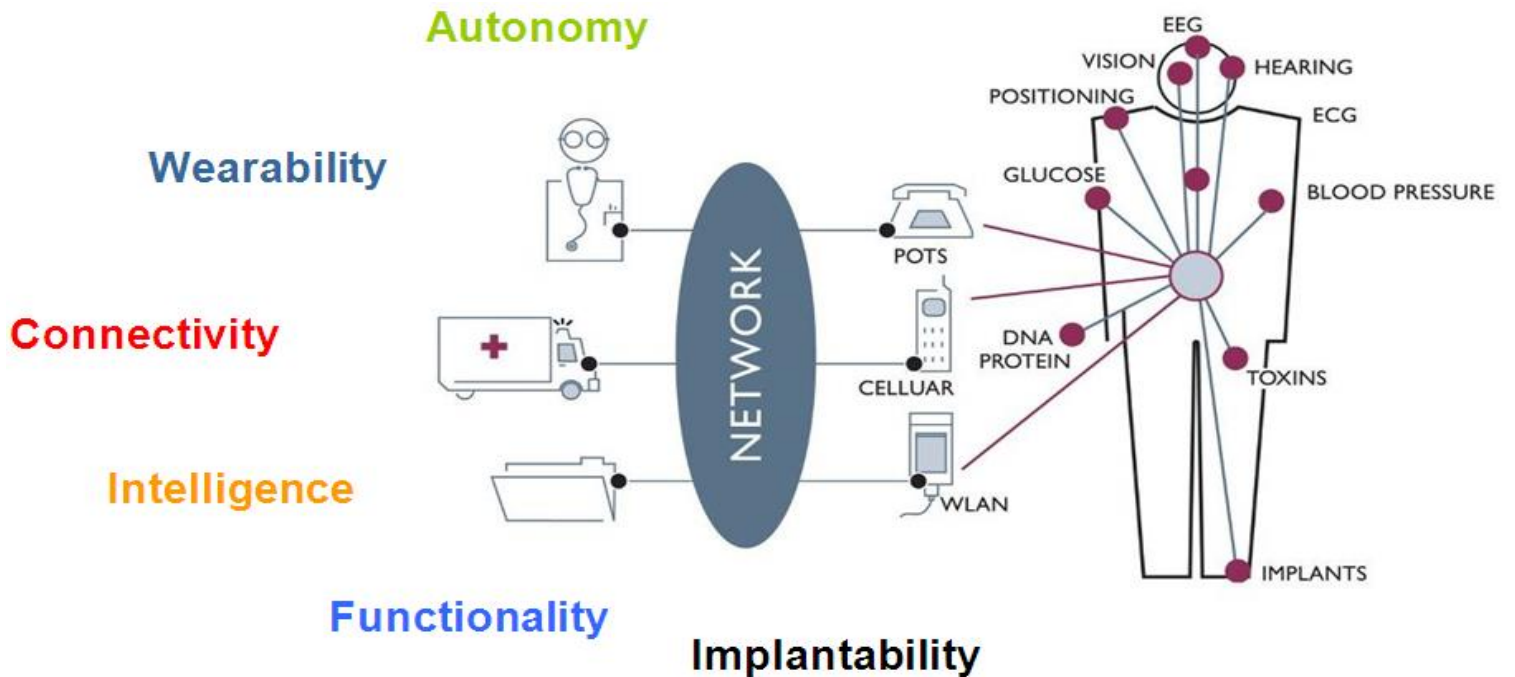
Technology drivers

- Ultra-low power
- Miniaturization
- Low cost processes



Thermal, Vibrational, RF, Light, Bio-chemical

From *Body* Area Network to *Personal Area Network*



Vehicles



Living spaces



Open spaces



Industry



Office buildings



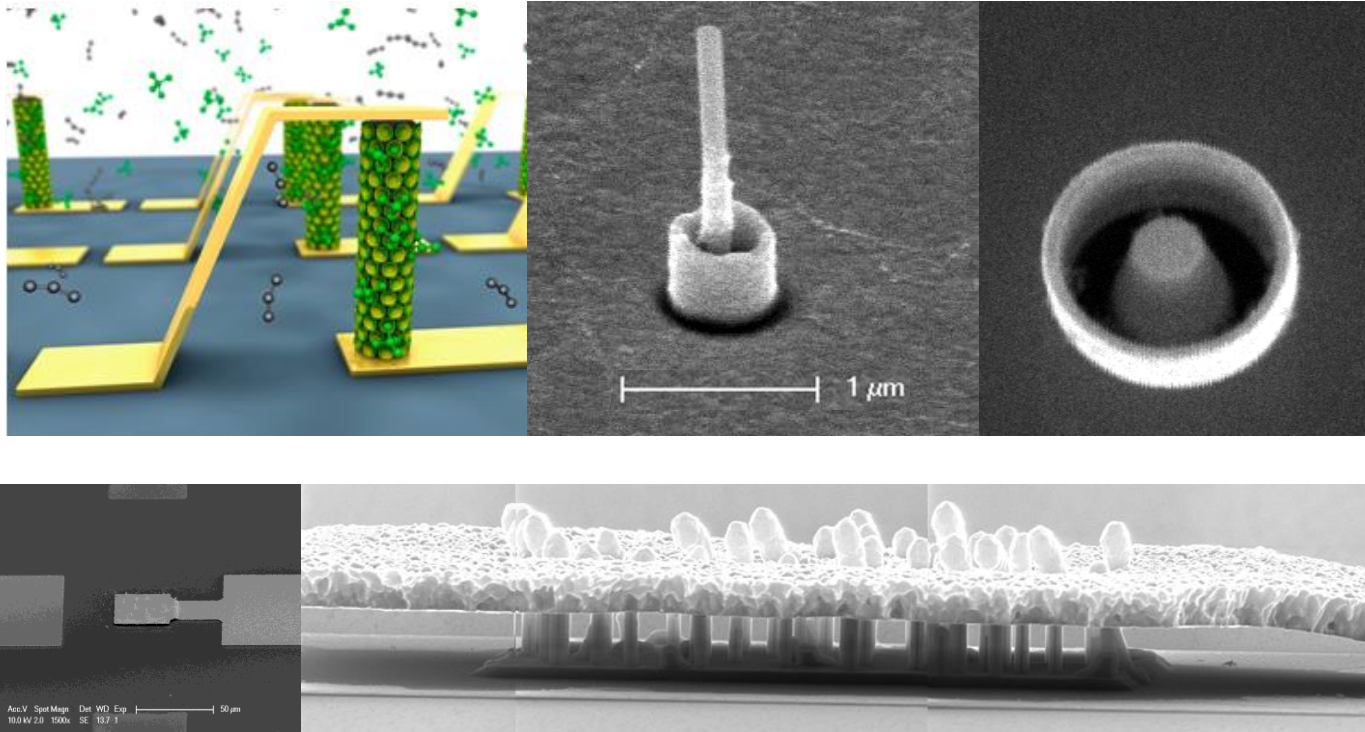
Working environment



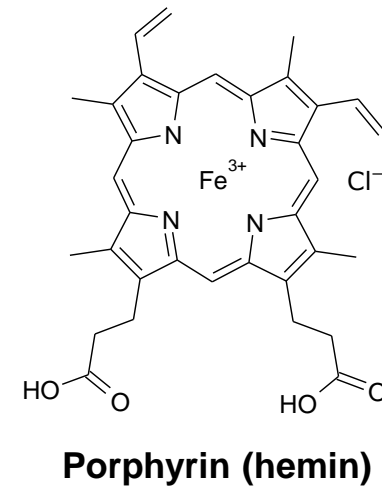
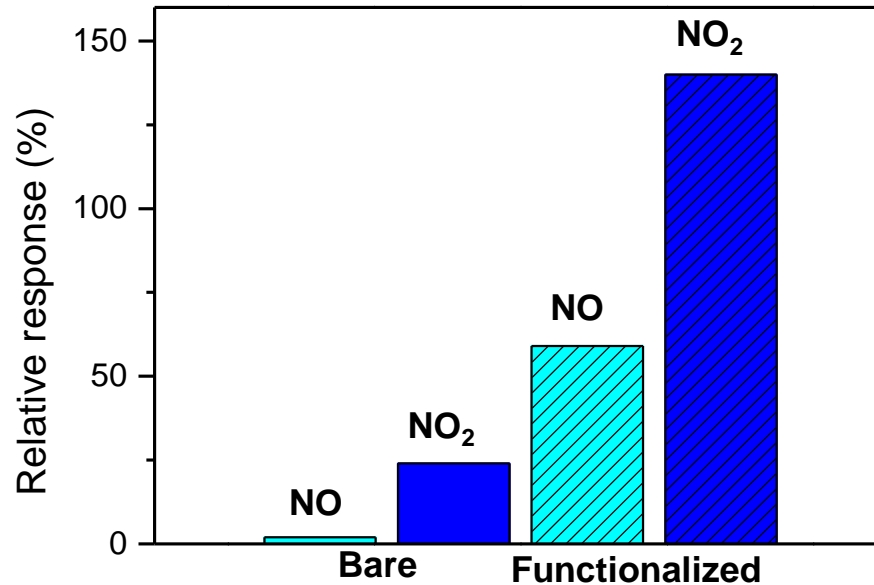
Extend with Compact chemical Sensors



Vertical nanowire devices



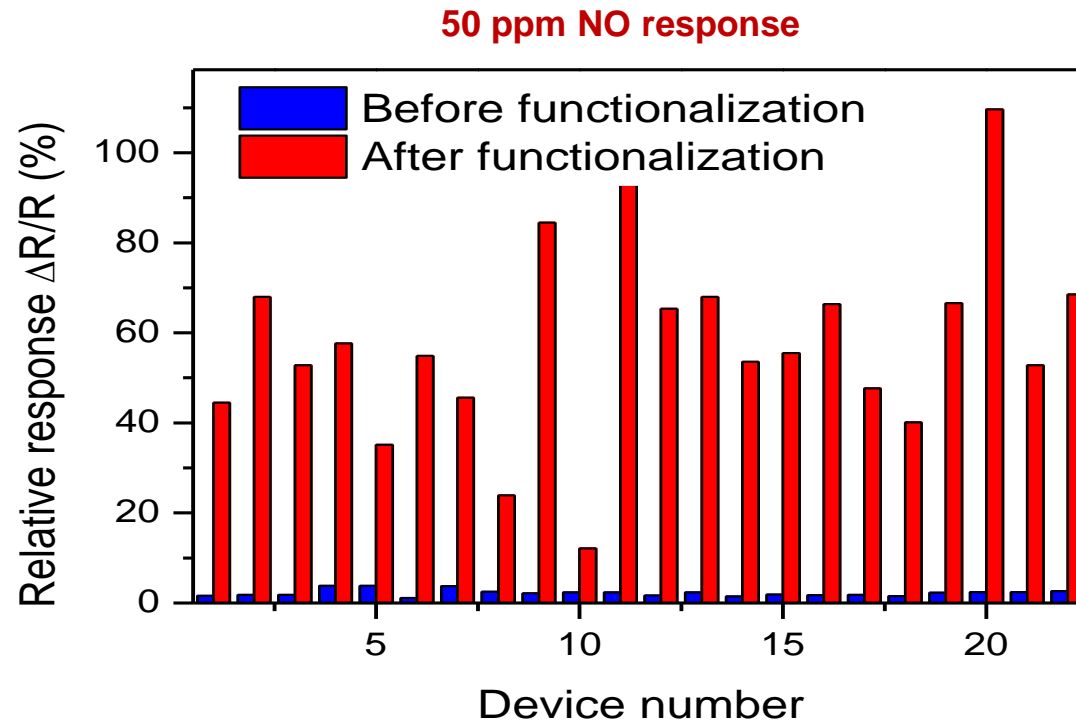
Response tunable through functionalization



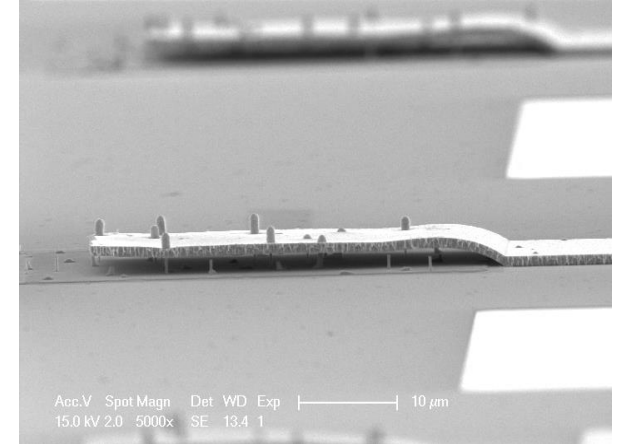
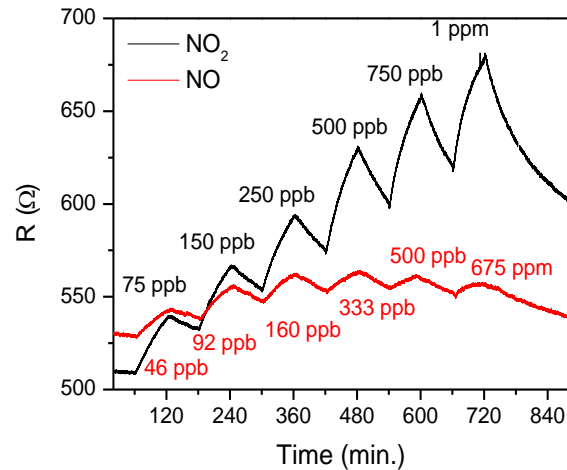
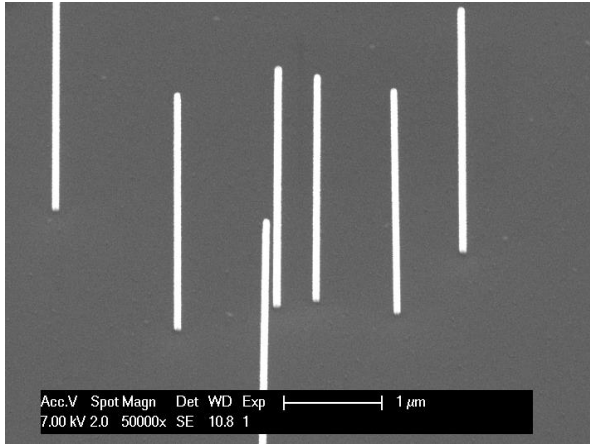
Ratio of NO and NO₂ response can be changed

Response can be increased

But not very reproducible



And why is InAs working so well ?



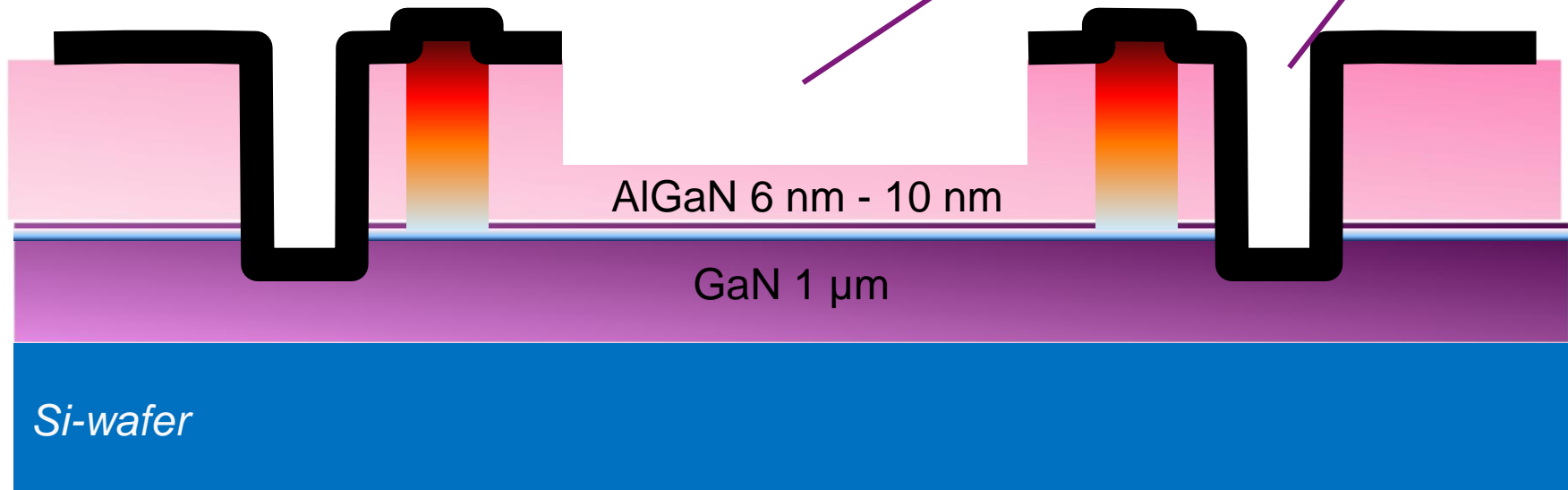
GaAs, GaP, **InAs**, InP, Si



Best performance related to surface HEMT....

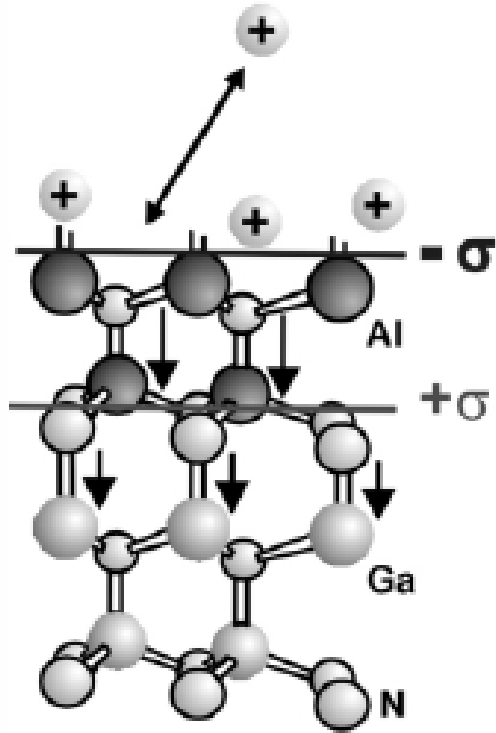
GaN Sensor Fabrication

- ▶ Etching of isolation trenches
- ▶ Deposition and RTA of the ohmic contacts
- ▶ Deposition of protective (isolation) layer
- ▶ Recess of the AlGaN-layer



Concept

Spontaneous polarization

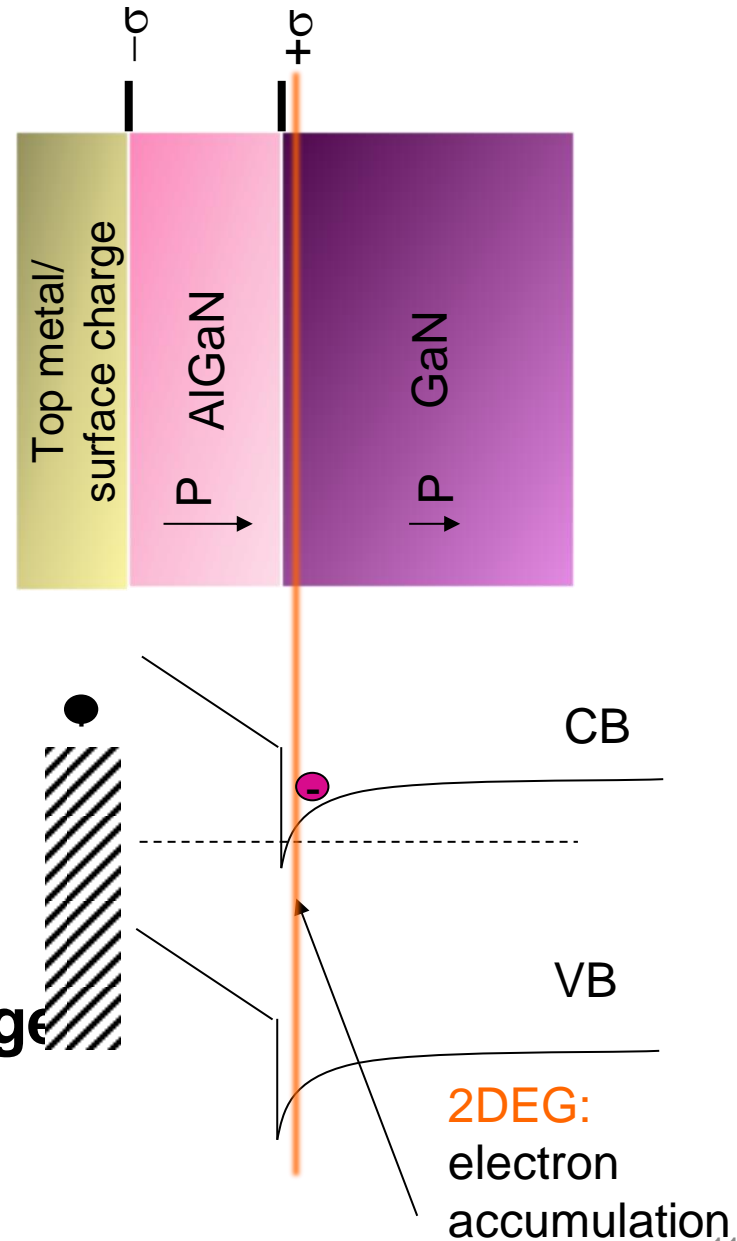


2DEG balanced by **surface charge**

Ionized surface donors

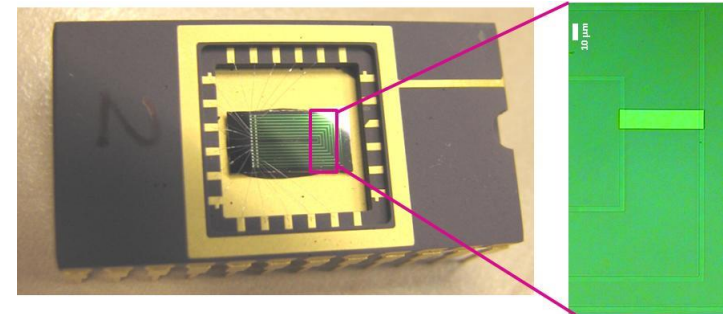
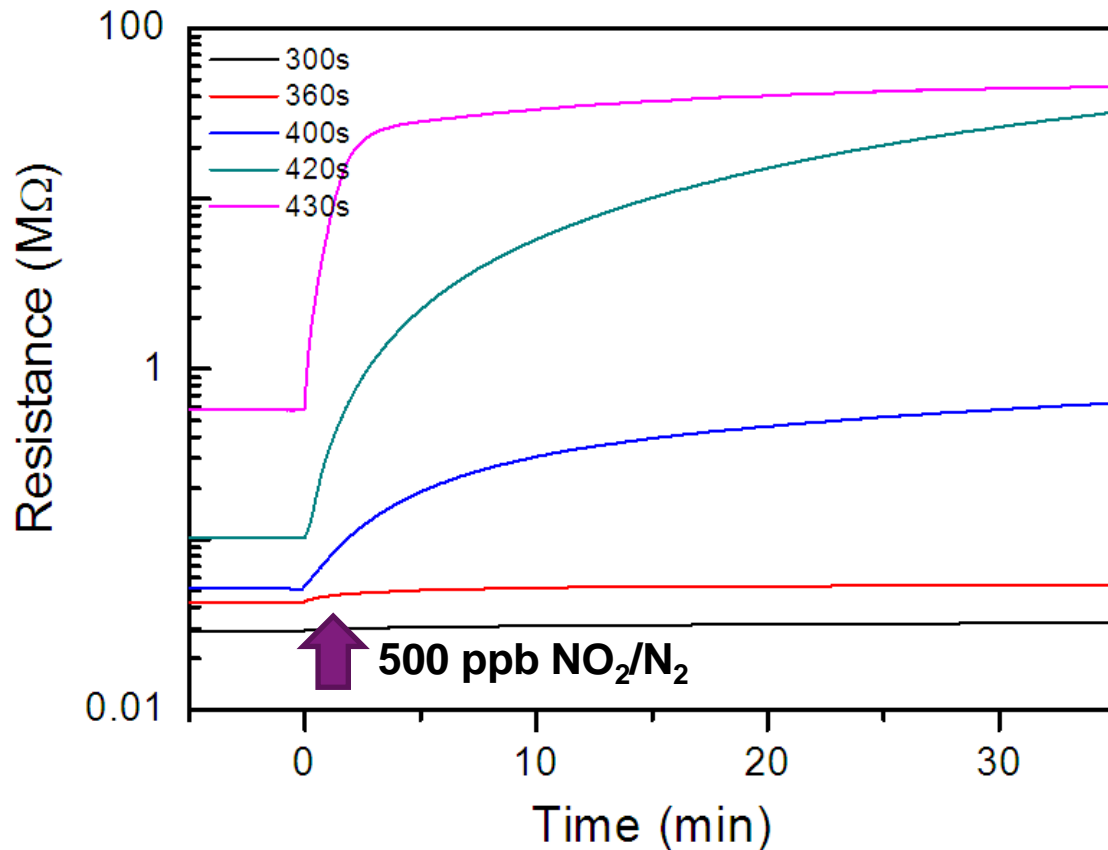


EUROPEAN COOPERATION IN SCIENCE AND TECHNOLOGY

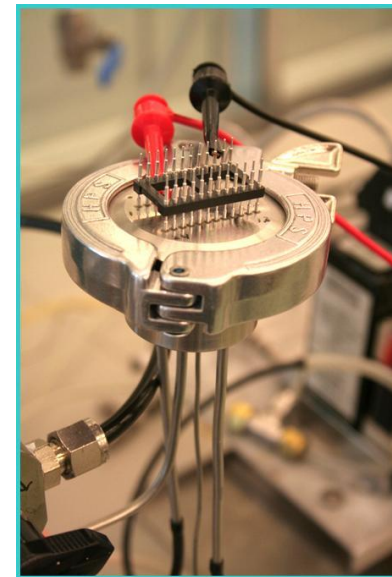


2DEG:
electron
accumulation

Effect of recess AlGaN



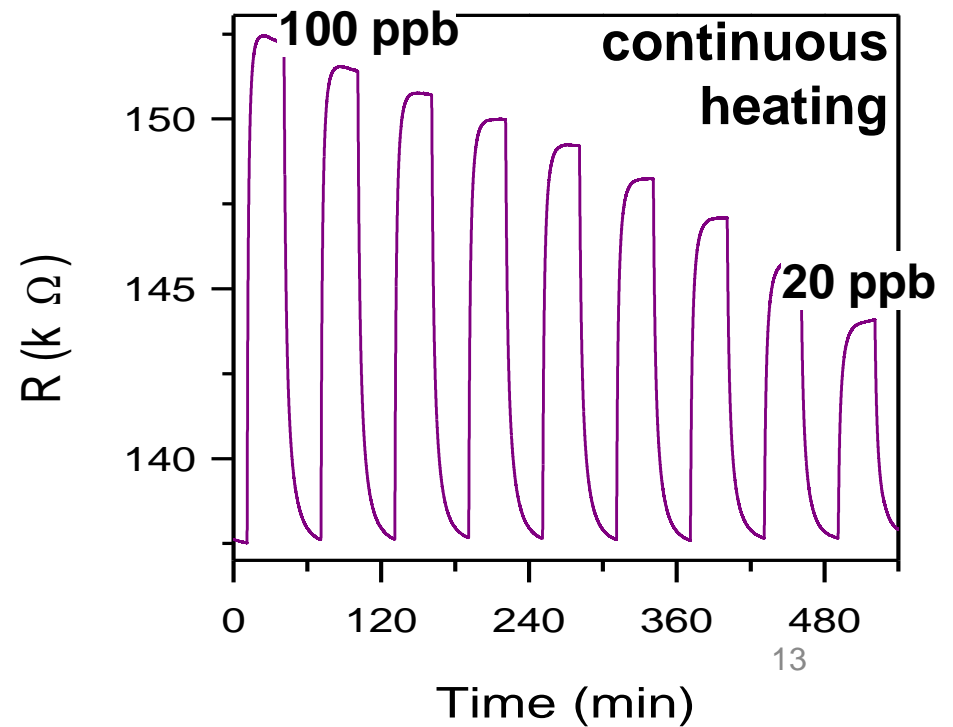
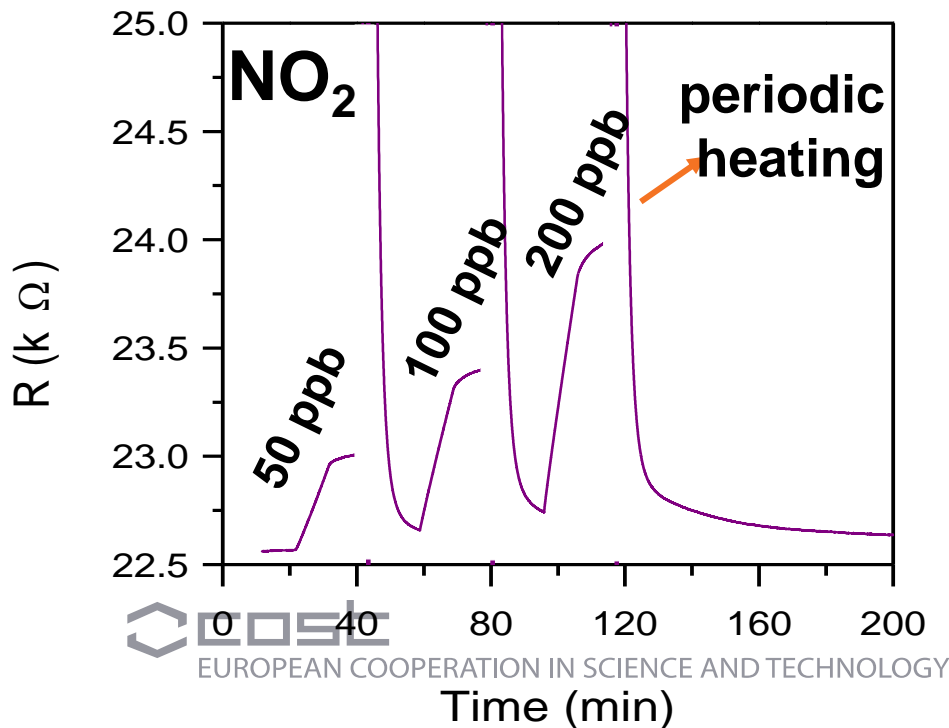
GaN sensor device mounted in DIL package. Inset shows recessed area with high NO₂ sensitivity (light green color).



Gas flow cell for fast device characterization

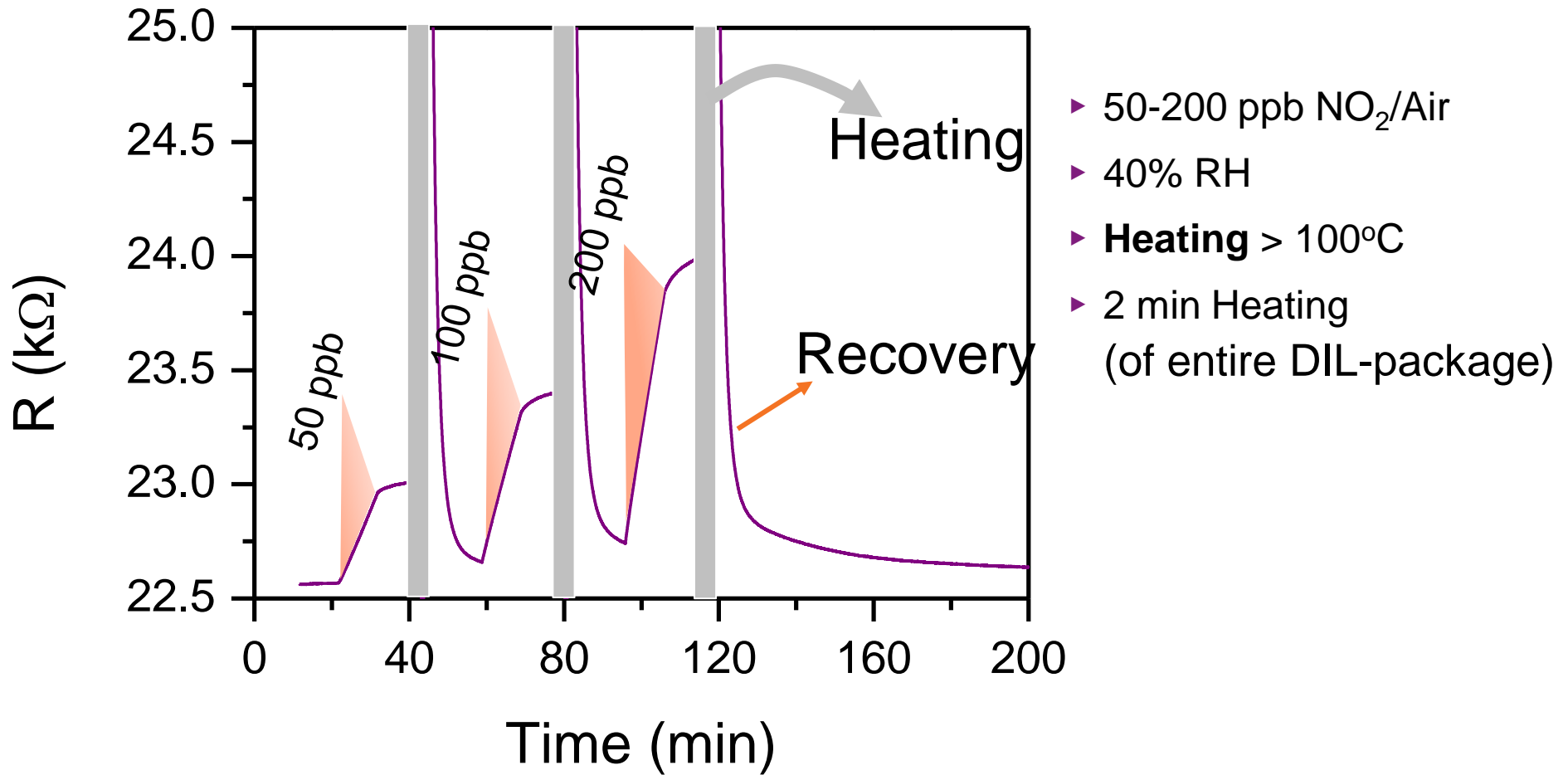
→ 100x increased sensitivity by recessing!

GAN FOR ENVIRONMENTAL SENSING



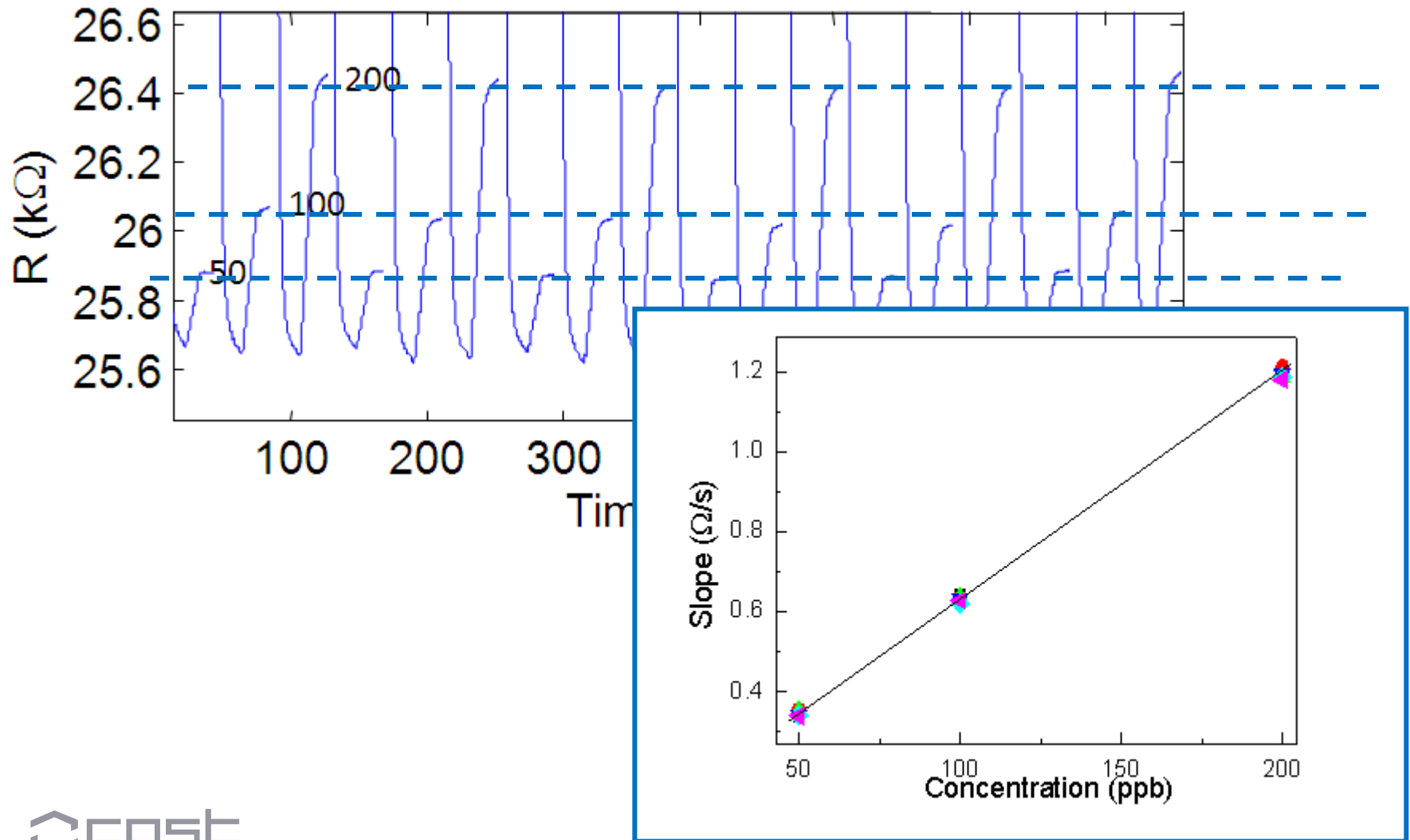
Solution: Slope-based detection

with Heating-assisted recovery

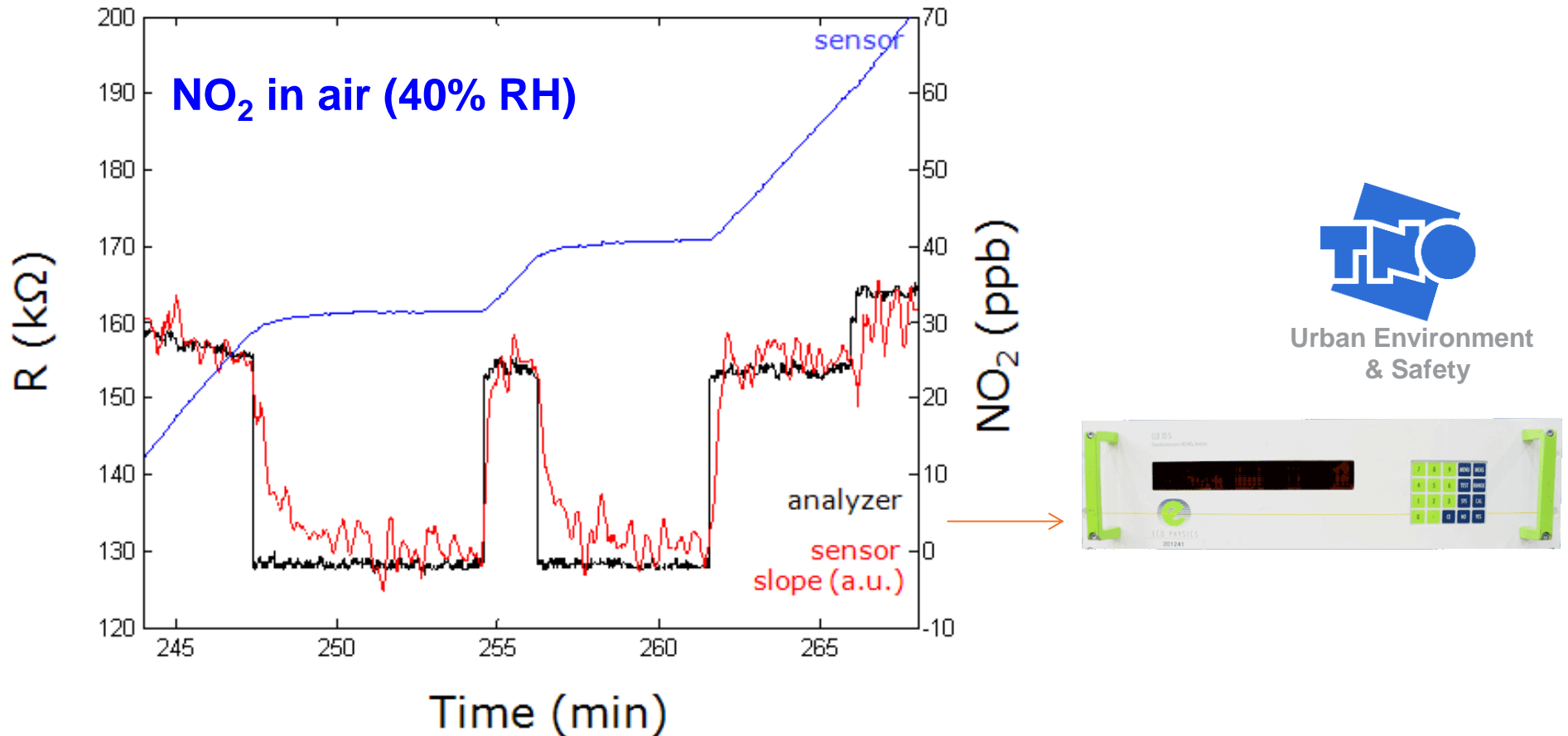


Full sensor recovery by heating within minutes

Solution: Slope-based detection with Heating-assisted recovery



Test: Comparison to chemiluminescence NO/NO2 analyzer



**→ Slope based detection allows FAST response
20 seconds for 25 ppb NO₂**

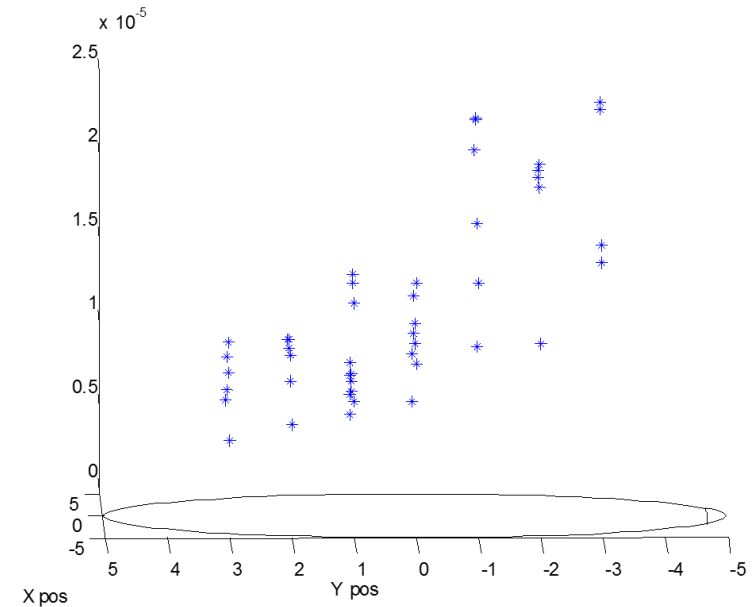
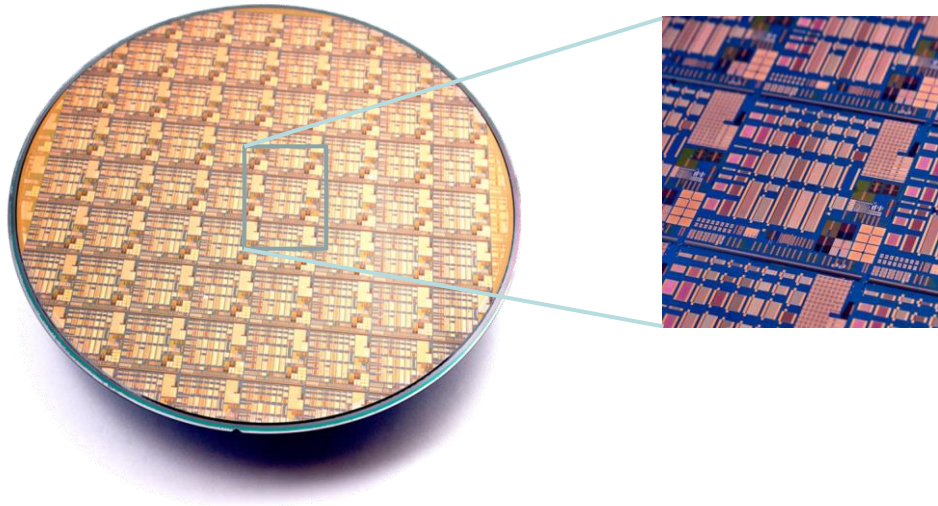


CROSS-SENSITIVITY & HUMIDITY

- **Cross-sensitivity testing for NO₂ 100 ppb in air 50%RH**
 - No cross-sensitivity up to 10% CO₂
 - No cross-sensitivity up to 200 ppm CO
 - No cross-sensitivity up to 50 ppb SO₂
 - No cross-sensitivity up to 200 ppb formaldehyde
 - Sensitivity to NO 20 to 50 times lower depending on operating temperature
 - Ozon testing in progress
- **Humidity testing performed under room temperature conditions as well as higher temperature (< 300° C)**
 - Sensitivity depends on humidity even at higher temperature
 - Calibration can deal with slow variations in humidity < 90%

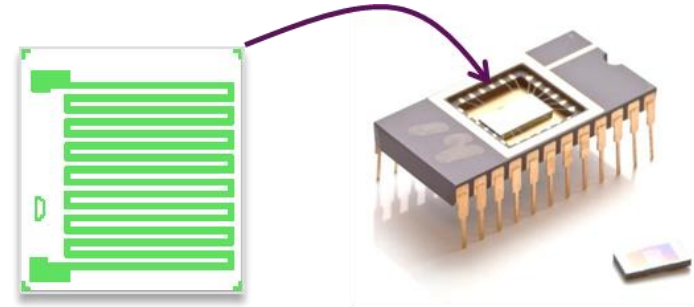
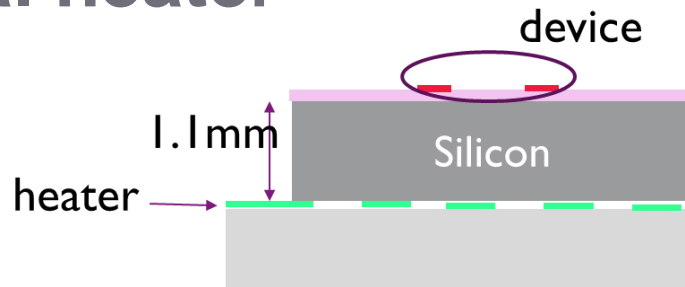
8" wafer fabrication

- Device fabrication has been scaled up to 8 inch wafers
- Processing compatible with power-FET
- Detection possible at room temperature (slope-based detection) as well as higher temperature.

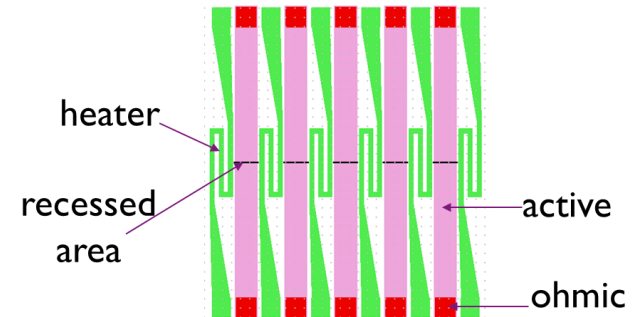
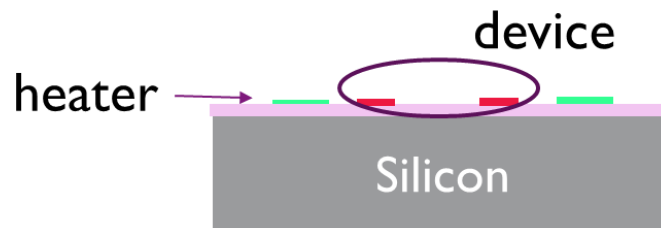


Reduce power consumption

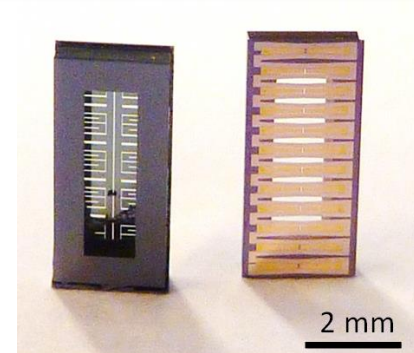
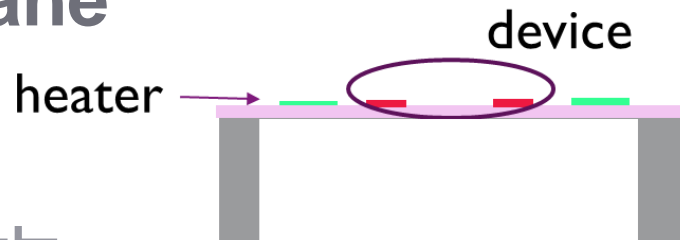
1 external heater



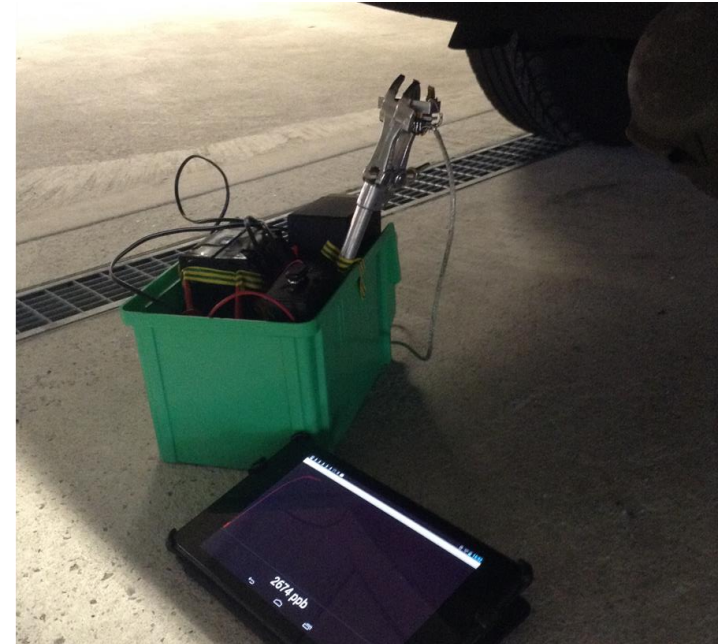
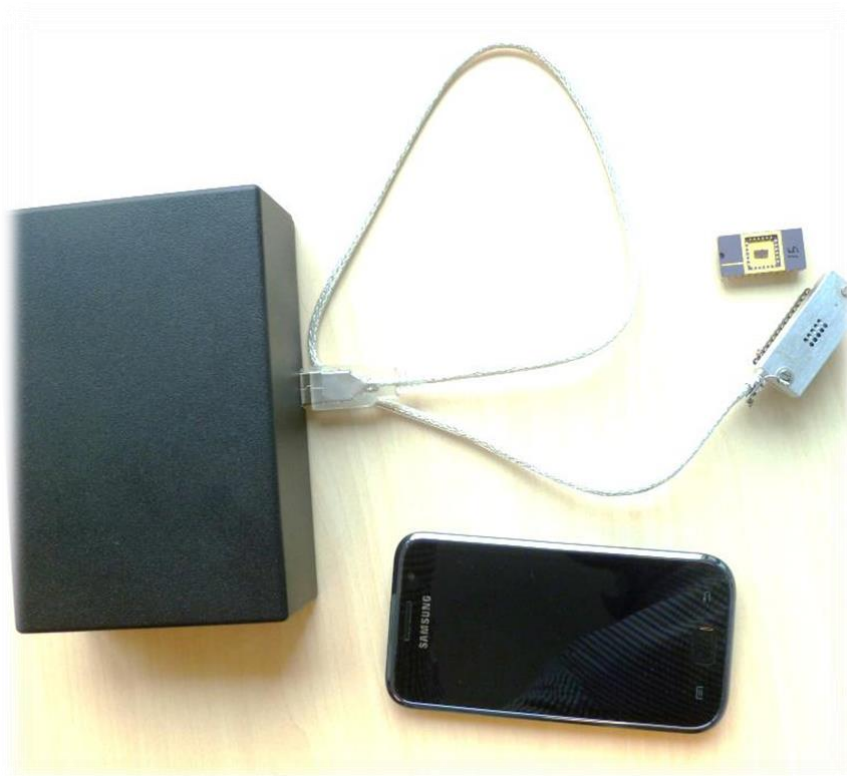
2 integrated heater



3 membrane



Sensor demo

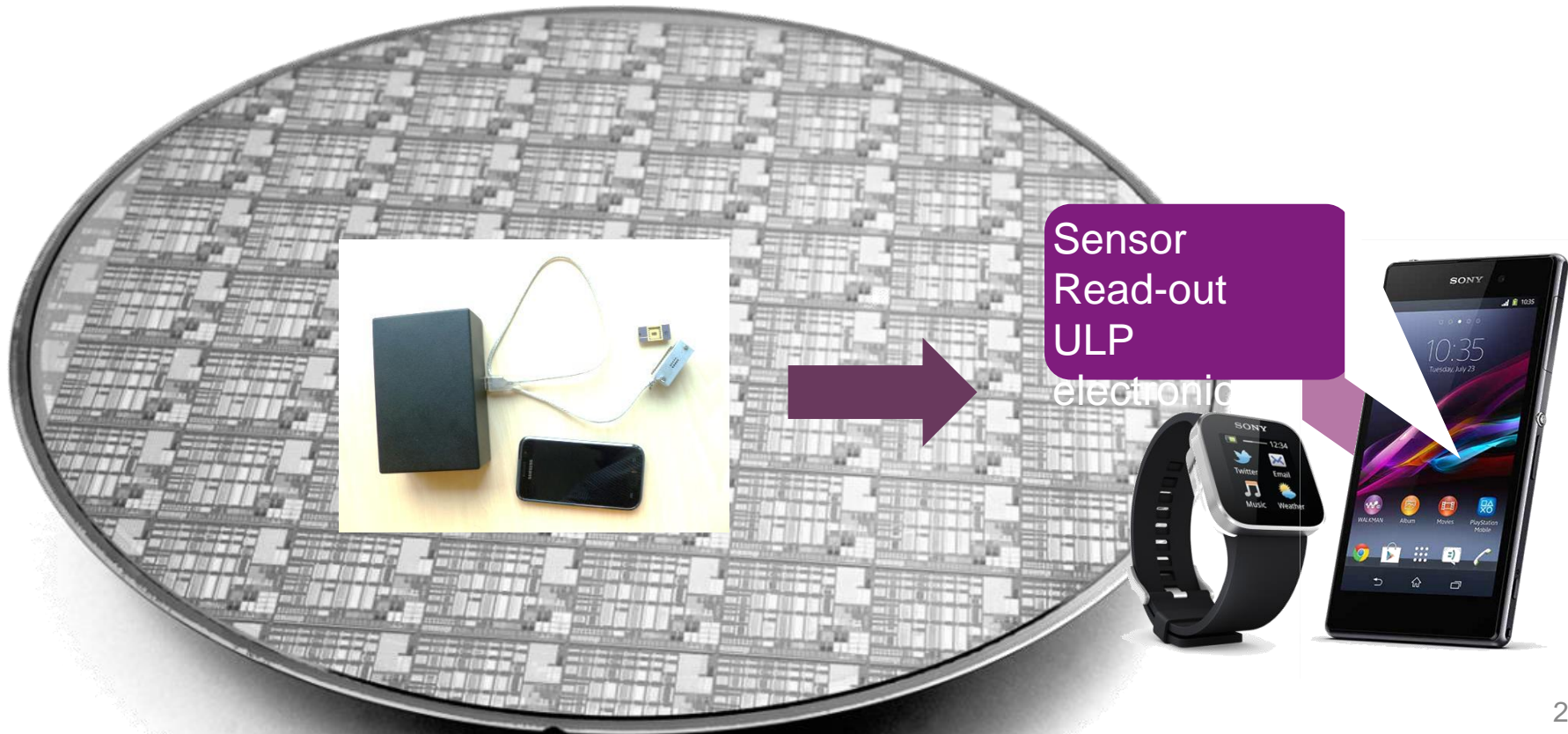


- Miniaturized sensor
- Hand-held sensor demo
- External heater
- Trial test results

GaN sensor PLATFORM

Handheld environmental sensor prototype

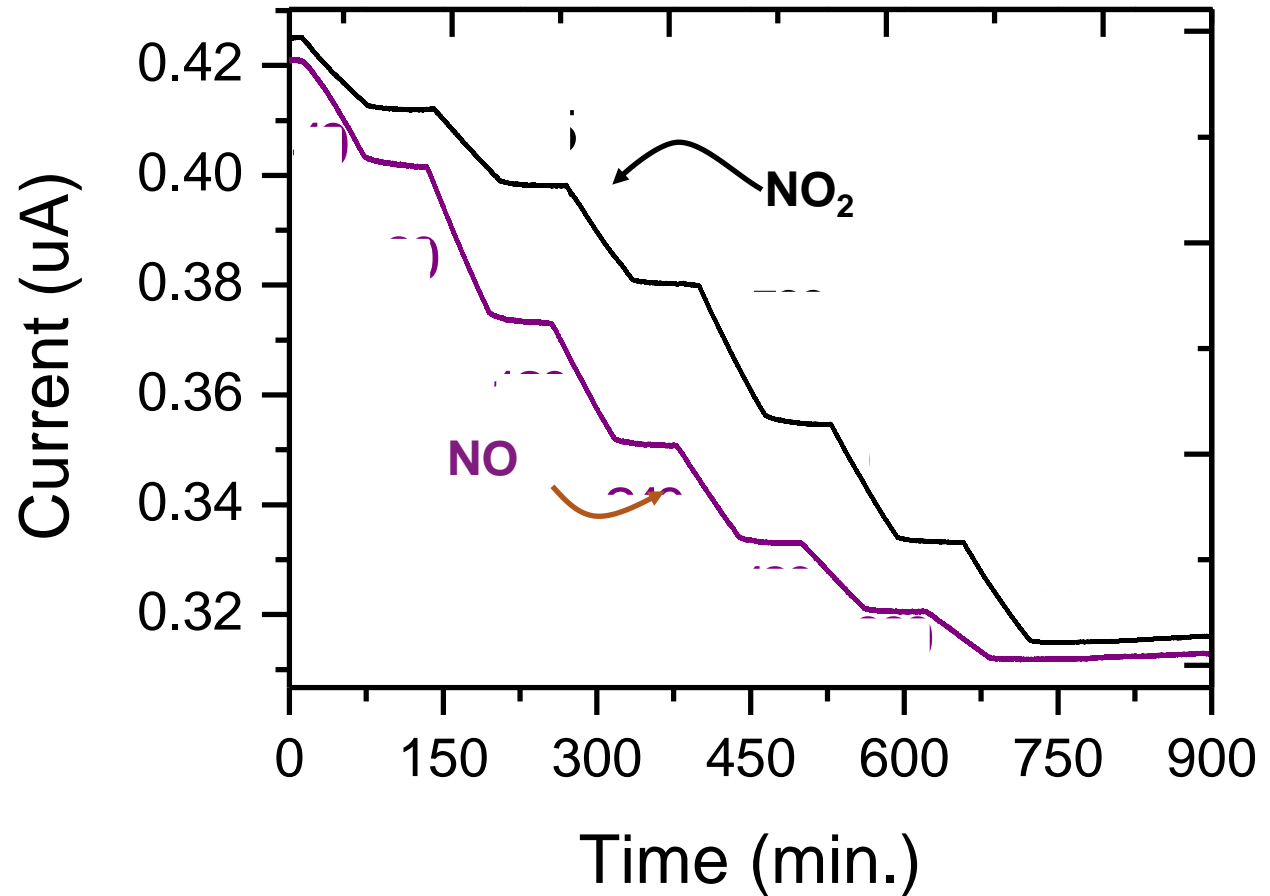
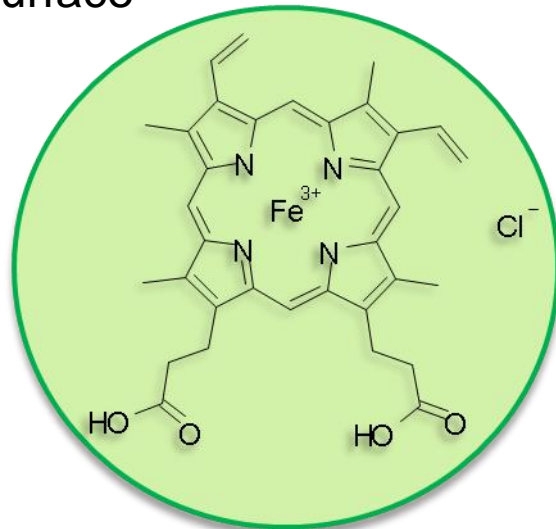
- Functionalization with polymers and metalorganic framework
- Transferable 8-inch process GaN-on-Si
- Usable for inorganic gasses- H_2 , O_3 , CO , SO_2 , CO_2 , NH_3 and hydrocarbons – CH_4 , C_2H_4 , Ethanol, Formaldehyde



Extending the platform to other gases

Functionalization of the surface with redox-active molecules (Porphyrin (hemin))

Formation of **charge transfer complex** induces a **dipole/charge redistribution** at the surface



CONCLUSIONS

- **GaN/AlGaN NO_x sensor development**
 - High sensitivity
 - Low cost environmental monitoring
 - 24/7 monitoring
- **Extend platform towards different gasses**
 - Extend to different gasses: NO, CO..
 - Functionalization (polymers, metal oxides)
- **Develop the gas sensor system in a small form factor**
 - Integrate read-out electronics
 - System in package
 - Application: integrate gas sensors in personal area network (PAN)